Kyung-Mun Kang

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Anion-controlled passivation effect of the atomic layer deposited ZnO films by F substitution to O-related defects on the electronic band structure for transparent contact layer of solar cell applications. Solar Energy Materials and Solar Cells, 2015, 132, 403-409.	6.2	47
2	Non-laminated growth of chlorine-doped zinc oxide films by atomic layer deposition at low temperatures. Journal of Materials Chemistry C, 2015, 3, 8336-8343.	5.5	22
3	Effect of Atomic Layer Deposition Temperature on the Growth Orientation, Morphology, and Electrical, Optical, and Band-Structural Properties of ZnO and Fluorine-Doped ZnO Thin Films. Journal of Physical Chemistry C, 2018, 122, 377-385.	3.1	22
4	Al/F codoping effect on the structural, electrical, and optical properties of ZnO films grown via atomic layer deposition. Applied Surface Science, 2021, 535, 147734.	6.1	21
5	The CO gas sensing properties of direct-patternable SnO ₂ films containing graphene or Ag nanoparticles. New Journal of Chemistry, 2015, 39, 2256-2260.	2.8	20
6	Study on properties of Ga/F-co-doped ZnO thin films prepared using atomic layer deposition. Thin Solid Films, 2018, 660, 913-919.	1.8	18
7	N-doped Al2O3 thin films deposited by atomic layer deposition. Thin Solid Films, 2018, 660, 657-662.	1.8	17
8	Oxygen vacancy-passivated ZnO thin film formed by atomic layer deposition using H2O2. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2018, 36, .	2.1	16
9	Low temperature method to passivate oxygen vacancies in un-doped ZnO films using atomic layer deposition. Thin Solid Films, 2018, 660, 852-858.	1.8	15
10	Enhanced hole injection into indium-free organic red light-emitting diodes by fluorine-doping-induced texturing of a zinc oxide surface. Journal of Materials Chemistry C, 2014, 2, 8344-8349.	5.5	12
11	Film thickness effect in c-axis oxygen vacancy-passivated ZnO prepared via atomic layer deposition by using H2O2. Applied Surface Science, 2020, 529, 147095.	6.1	12
12	The role of oxygen defects engineering via passivation of the Al2O3 interfacial layer for the direct growth of a graphene-silicon Schottky junction solar cell. Applied Materials Today, 2022, 26, 101267.	4.3	11
13	Thickness-dependent growth orientation of F-doped ZnO films formed by atomic layer deposition. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2016, 34, .	2.1	10
14	Structural, electrical, and optical properties of Si-doped ZnO thin films prepared via supercycled atomic layer deposition. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2021, 273, 115401.	3.5	9
15	Structural, Electrical, and Optical Properties of Photochemical Metal-Organic-Deposited ZnO Thin Films Incorporated with Ag Nanoparticles and Graphene. ECS Journal of Solid State Science and Technology, 2015, 4, N55-N59.	1.8	6
16	Directly patternable SnO2 thin films incorporating Pt nanoparticles. Materials Research Bulletin, 2014, 52, 6-10.	5.2	4
17	Effect of Hydrogen Doping on the Gateâ€Tunable Memristive Behavior of Zinc Oxide Films with and without F or N Doping. Physica Status Solidi (A) Applications and Materials Science, 2021, 218, 2000702.	1.8	4
18	Effective Oxygen-Defect Passivation in ZnO Thin Films Prepared by Atomic Layer Deposition Using Hydrogen Peroxide. Journal of the Korean Ceramic Society, 2019, 56, 302-307.	2.3	4

#	Article	IF	CITATIONS
19	In Situ Incorporation of Pt Nanoparticles in Fluorine-doped SnO2 Nanocomposite Thin Films by a One-step Synthesis. Chemistry Letters, 2015, 44, 782-784.	1.3	1
20	Thickness-dependent Electrical, Structural, and Optical Properties of ALD-grown ZnO Films. Journal of the Microelectronics and Packaging Society, 2014, 21, 31-35.	0.1	1